

30A 400V Fast recovery diode

1 Description

30A, 400V Ultrafast Diodes They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction. These devices are intended for use as energy steering/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor

TO-220F/3PF provides insulation voltage rated at 2000V RMS from all three terminals to external heatsink.

2 Features

- Low power loss,
- high efficiency Low forward voltage,
- high current capability High surge capacity
- Super fast recovery times
- high voltage

3 Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose

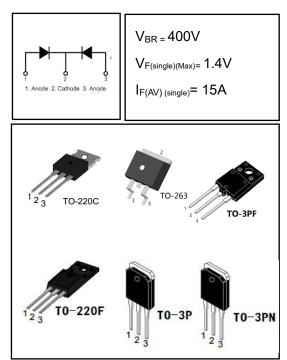
4 Electrical Characteristics

4.1 Absolute Maximum Ratings (Tc=25°C, unless otherwise noted)

PARA	PARAMETER			SYMBO	VALUE	UNIT
Peak Repetitive Reverse Voltage			VRRM	400	V	
Working Peak Reverse Voltage			V _{RWM}	400	V	
DC Blocking Voltage			V _R	400	V	
Average Restified Forward Current	(single)	TO-220F/3PF	Tc=100℃		15	А
Average Rectified Forward Current	(double)	e) TO-220/3P/263 T _C =135℃		I _{F(AV)}	30	А
Repetitive Peak Surge Current(single)			I _{FRM}	20	А
Nonrepetitive Peak Surge Current(s	Nonrepetitive Peak Surge Current(single) t _p =8.3ms			I _{FSM}	180	A
Avalanche Energy(single) L=1mH			Eas	20	mJ	
Operating Junction Temperature Range			Tj	-55~150	°C	
Storage Temperature Range				T _{stg}	-55~150	°C

4.2 Thermal Characteristics

PARAMETER	SYMBOL		VAL	UE	UNIT	
PARAMETER	STWBUL	TO-220F	TO-220	TO-3P/3PN	TO-3PF	UNIT
Thermal Resistance, Junction to Case-sink	R _{thJC}	2.5	1.8	0.8	1.5	°C/W





MUR3040NCS

4.3 Electrical Characteristics	(Tc=25℃,unless otherwise noted)
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PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Maximum Instantaneous	VF	I _F =15A	-	1.25	1.40	V
Forward Voltage		I _F =15A, T _C = 150℃	-	-	1.30	V
		I _F = 20A	-	1.38	1.5	V
Maximum Instantaneous	IR	V _R = 400V	-	-	5	uA
Reverse		V _R = 400V, TC = 150℃	-	-	1	mA
Maximum Reverse	trr	V _R =30V IF=1A -dI/dt=50A/us	-	26	35	ns
Recovery Time						
Total capacitance	Ctot	V _R =0V f=1MHz	-	205	-	pF
DC Blocking Voltage	V _{BR}	I _R =100uA	410	440	-	V

DEFINITIONS

VF = Instantaneous forward voltage (pw = 300µs, D = 2%).

IR = Instantaneous reverse current.

 $R\theta JC$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

5 Typical characteristics diagrams

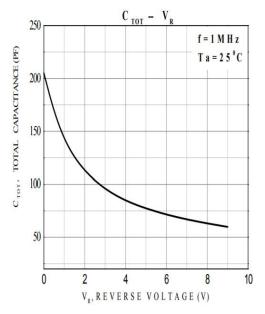


FIGURE 1. Total capacitance vs Voltage

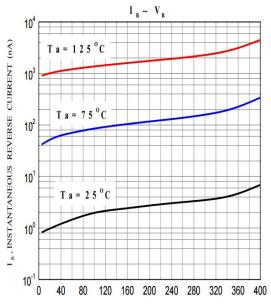
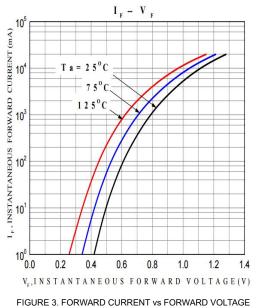
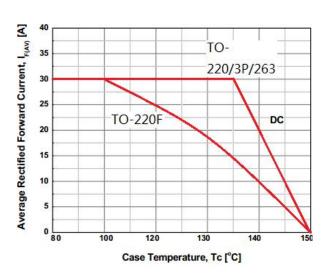


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE



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6 Typical Test Circuit and Waveform

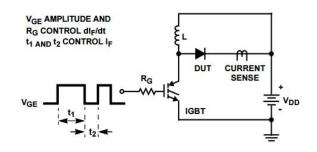


FIGURE 5. trr TEST CIRCUIT

 $\begin{array}{l} {\sf R} < 0.1 \Omega \\ {\sf E}_{{\sf AVL}} = 1/2 L l^2 \left[{\sf V}_{{\sf R}({\sf AVL})} / ({\sf V}_{{\sf R}({\sf AVL})} \cdot {\sf V}_{{\sf DD}}) \right] \end{array}$

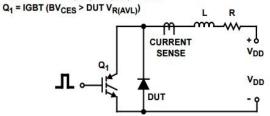


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT FIGURE

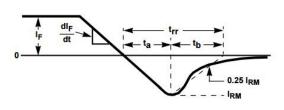


FIGURE 6. trr WAVEFORMS AND DEFINITIONS

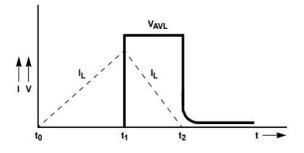
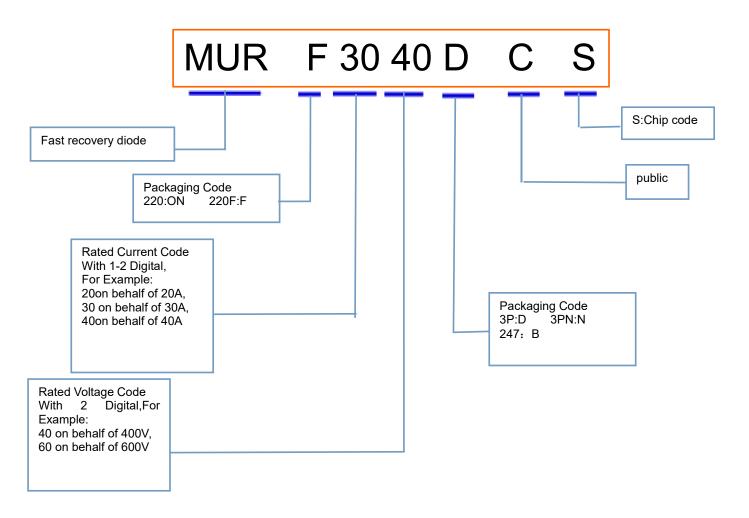


FIGURE8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



7 Product Names Rules



8 Product Specifications and Packaging Models

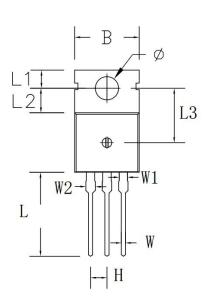
Product Model	Package Type	Mark Name	RoHS	Package	Quantity
MUR3040CS	TO-220	MUR3040CS	Pb-free	Tube	1000/box
MURF3040CS	TO-220F	MURF3040CS	Pb-free	Tube	1000/box
MUR3040DCS	TO-3P	MUR3040DCS	Pb-free	Tube	300/box
MUR3040NCS	TO-3PN	MUR3040NCS	Pb-free	Tube	300/box
MUR3040FCS	TO-3PN	MUR3040FCS	Pb-free	Tube	300/box

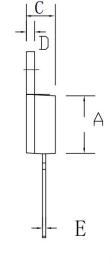




9 **Dimensions**

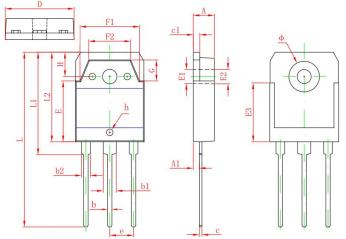
TO-220 PACKAGE OUTLINE DIMENSIONS





Courts of 1	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
А	8.80	9.30	0.346	0.366
В	9.70	10.30	0.382	0.406
С	4.25	4.75	0.167	0.187
D	1.20	1.45	0.047	0.057
Е	0.40	0.60	0.016	0.024
Н	2.54 TYP		0.100 TYP	
W	0.60	0.95	0.024	0.037
W1	1.05	1.45	0.041	0.057
W2	1.20	1.60	0.047	0.063
L	12.60	13.40	0.496	0.528
L1	2.45	2.95	0.096	0.116
L2	3.45	3.95	0.136	0.156
L3	8.15	8.65	0.321	0.341
Φ	3, 50	3.90	0.138	0.154

TO-3PN PACKAGE OUTLINE DIMENSIONS

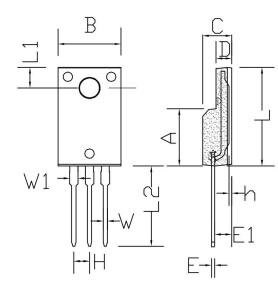


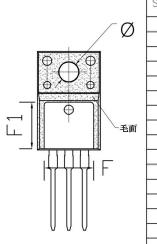
Cum hal	Dimensions	In Millimeters	Dimension	s in inches
Symbol	Min	Max	Min	Max
A	4.600	5.000	0.181	0.197
A 1	2.200	2.600	0.087	0.102
b	0.800	1.200	0.031	0.047
b 1	2.800	3.200	0.110	0.126
b 2	1.800	2.200	0.071	0.087
С	0.500	0.700	0.020	0.028
c1	1.450	1.650	0.057	0.065
D	15.450	15.850	0.608	0.624
E	13.700	14.100	0.539	0.555
E 1	3.200 REF		0.126 REF	
E 2	3.300 REF		0.130 REF	
E 3	13.45	0 REF	0.530 REF	
F 1	13.400	13.800	0.528	0.543
F 2	9.400	9.800	0.370	0.386
L	39.900	40.300	1.571	1.587
L1	23.200	23.600	0.913	0.929
L2	20.300	20.600	0.799	0.811
Φ	6.900	7.100	0.272	0.280
G	5.150	5.550	0.203	0.219
е	5.450	D TYP	0.21	5 TYP
Н	5.000	REF	0.19	7 REF
h	0.000	0.300	0.000	0.012



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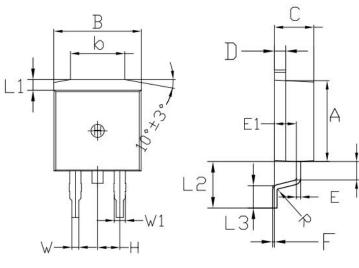
TO-220F PACKAGE OUTLINE DIMENSIONS





	DimensionsIn	Millimatora	Dimension	
Symbol				
	min.	max.	min.	max.
A	8.80	9.30	0.346	0.366
В	10.00	10.50	0.394	0.413
С	4.30	4.90	0.169	0.193
D	2.30	2.70	0.091	0.106
L	15.55	16.15	0.612	0.636
h	0.40	0.60	0.016	0.024
L1	3.15	3.55	0.124	0.140
L2	12.65	13.35	0.498	0.526
W	0.70	0.90	0.028	0.035
W1	1.15	1.55	0.045	0.061
Н	2.54	TYP	0.100	TYP
E	0.48	0.53	0.019	0.021
φ	2.90	3.40	0.114	0.134
E1	2.40	2.90	0.094	0.114
F	7.75	8.25	0.305	0.325
F1	7.35	7.85	0.289	0.309

TO-263 PACKAGE OUTLINE DIMENSIONS

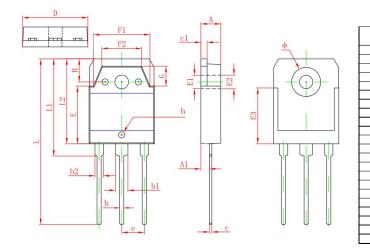


Cumb a 1	Dimensions I	n Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
A	8.80	9.30	0.346	0.366
В	9.70	10.30	0.382	0.406
С	4.25	4.75	0. 167	0.187
D	1.20	1.45	0.047	0.057
E	0.40	0.60	0.016	0.024
L	12.25	13.75	0.482	0.541
L1	1.15	1.45	0.045	0.057
R	0.24	0.26	0.0095	0.0102
W	0.80	0.82	0.0315	0.0323
W1	1.20	1.30	0.047	0.051
Н	2.	54 TYP	0. 200 TYP	
b	5.50	6.50	0.216	0.256
E1	2.4	2.6	0.0946	0.1024
L2	5.20	5.80	0.205	0.228
L3	2.20	3.20	0.087	0.126
F	0.03	0.23	0.0012	0.0091



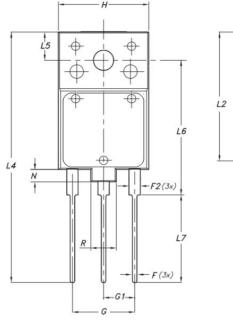


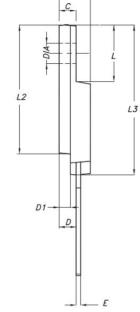
TO-3PN PACKAGE OUTLINE DIMENSIONS



0	Dimensions	In Millimeters	Dimension	s in inches
Symbol	M in	Max	Min	Max
A	4.600	5.000	0.181	0.197
A 1	2.200	2.600	0.087	0.102
b	0.800	1.200	0.031	0.047
b 1	2.800	3.200	0.110	0.126
b 2	1.800	2.200	0.071	0.087
С	0.500	0.700	0.020	0.028
c1	1.450	1.650	0.057	0.065
D	15.450	15.850	0.608	0.624
E	13.700	14.100	0.539	0.555
E 1	3.200 REF		0.126 REF	
E 2	3.300	REF	0.130 REF	
E 3	13.45	0 REF	0.530 REF	
F1	13.400	13.800	0.528	0.543
F 2	9.400	9.800	0.370	0.386
L	39.900	40.300	1.571	1.587
L1	23.200	23.600	0.913	0.929
L2	20.300	20.600	0.799	0.811
Φ	6.900	7.100	0.272	0.280
G	5.150	5.550	0.203	0.219
е	5.450	TYP	0.21	TYP
Н	5.000	REF	0.197	REF
h	0.000	0.300	0.000	0.012

TO-3PF PACKAGE OUTLINE DIMENSIONS





Dim.		mm	
vim.	Min.	Тур.	Max.
A	5.30		5.70
С	2.80		3.20
D	3.10		3.50
D1	1.80		2.20
E	0.80		1.10
F	0.65		0.95
F2	1.80		2.20
G	10.30		11.50
G1		5.45	
н	15.30		15.70
L	9.80	10	10.20
L2	22.80		23.20
L3	26.30		26.70
L4	43.20		44.40
L5	4.30		4.70
L6	24.30		24.70
L7	14.60		15
N	1.80		2.20
R	3.80		4.20
Dia	3.40		3.80



10 Attentions

- Jiangsu Donghai Semiconductor Technology Co., Ltd. reserves the right to change the specification without prior notice! The customer should obtain the latest version of the information before making the order and verify that the information is complete and up to date.
- It is the responsibility of the purchaser for any failure or failure of any semiconductor product under certain conditions. It is the responsibility of the purchaser to comply with safety standards and to take safety measures in the system design and machine manufacturing of WXDH products in order to avoid potential risk of failure. Injury or property damage.
- Product promotion is endless, our company will be dedicated to provide customers with better products.

11 Appendix

Revision history:

Date	REV.	Description	Page
2019.07.22	1.0	Original	